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Jameco Part Number 24117ONS

# Micropower Voltage Reference Diodes

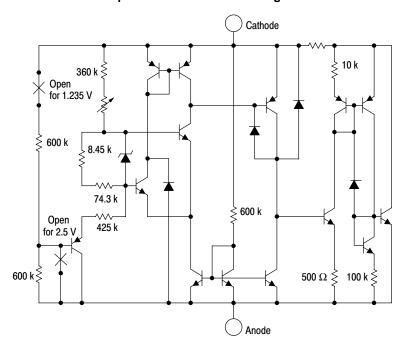
The LM285/LM385 series are micropower two-terminal bandgap voltage regulator diodes. Designed to operate over a wide current range of 10  $\mu$ A to 20 mA, these devices feature exceptionally low dynamic impedance, low noise and stable operation over time and temperature. Tight voltage tolerances are achieved by on-chip trimming. The large dynamic operating range enables these devices to be used in applications with widely varying supplies with excellent regulation. Extremely low operating current make these devices ideal for micropower circuitry like portable instrumentation, regulators and other analog circuitry where extended battery life is required.

The LM285/LM385 series are packaged in a low cost TO-226AA plastic case and are available in two voltage versions of 1.235 and 2.500 V as denoted by the device suffix (see Ordering Information table). The LM285 is specified over a -40°C to +85°C temperature range while the LM385 is rated from 0°C to +70°C.

The LM385 is also available in a surface mount plastic package in voltages of 1.235 and 2.500 V.

- Operating Current from 10 μA to 20 mA
- 1.0%, 1.5%, 2.0% and 3.0% Initial Tolerance Grades
- Low Temperature Coefficient
- 1.0 Ω Dynamic Impedance
- Surface Mount Package Available

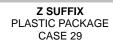
#### Representative Schematic Diagram





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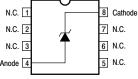


N.C. Cathode Anode

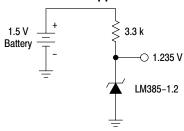








#### **Standard Application**



#### **ORDERING INFORMATION**

Device	Operating Temperature Range	Reverse Break- down Voltage	Tolerance
LM285D-1.2 LM285Z-1.2	T <sub>A</sub> = -40° to	1.235 V	±1.0%
LM285D-2.5 LM285Z-2.5	+85°C	2.500 V	±1.5%
LM385BD-1.2 LM385BZ-1.2		1.235 V	±1.0%
LM385D-1.2 LM385Z-1.2	T <sub>A</sub> = 0° to +70°C	1.235 V	±2.0%
LM385BD-2.5 LM385BZ-2.5		2.500 V	±1.5%
LM385D-2.5 LM385Z-2.5		2.500 V	±3.0%

# **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ , unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Current	I <sub>R</sub>	30	mA
Forward Current	I <sub>F</sub>	10	mA
Operating Ambient Temperature Range LM285 LM385	T <sub>A</sub>	- 40 to + 85 0 to +70	°C
Operating Junction Temperature	TJ	+ 150	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ , unless otherwise noted)

		LM285-1.2		LM385-1.2/LM385B-1.2				
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
$\label{eq:Reverse Breakdown Voltage (I_{Rmin} \leqslant I_{R} \leqslant 20 \text{ mA})} \\ LM285-1.2/LM385B-1.2 \\ T_{A} = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\ LM385-1.2 \\ T_{A} = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\$	V <sub>(BR)R</sub>	1.223 1.200	1.235 - -	1.247 1.270 -	1.223 1.210 1.205 1.192	1.235 - 1.235	1.247 1.260 1.260 1.273	V
Minimum Operating Current $T_{A} = 25^{\circ}C$ $T_{A} = T_{low} \text{ to } T_{high} \text{ (Note 1)}$	I <sub>Rmin</sub>		8.0	10 20		8.0	15 20	μΑ
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq 1.0$ mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1) $1.0$ mA $\leq I_R \leq 20$ mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1)	ΔV <sub>(BR)R</sub>	- - -	- - -	1.0 1.5 10 20	- - -	- - -	1.0 1.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu A, T_A = +25^{\circ}C$	Z		0.6	-	-	0.6	-	Ω
Average Temperature Coefficient 10 $\mu$ A $\leq$ I <sub>R</sub> $\leq$ 20 mA, T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 1)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/°C
Wideband Noise (RMS) $I_R = 100 \ \mu\text{A}, \ 10 \ \text{Hz} \le f \le 10 \ \text{kHz}$	n	-	60	-	-	60	-	μV
Long Term Stability $I_R = 100 \ \mu\text{A}, \ T_A = +25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$	S	-	20	-	-	20	-	ppm/ kHR

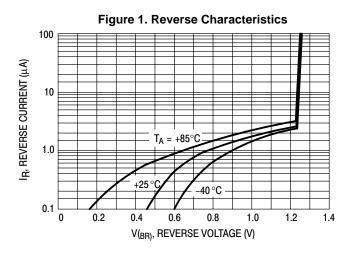
### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C, unless otherwise noted)

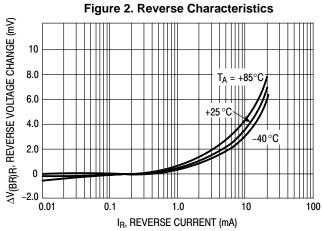
		LM285-2.5		LM385-2.5/LM385B-2.5				
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Reverse Breakdown Voltage ( $I_{Rmin} \le I_{R} \le 20 \text{ mA}$ )	V <sub>(BR)R</sub>							V
LM285-2.5/LM385B-2.5		2.462	2.5	2.538	2.462	2.5	2.538	
$T_A = T_{low}$ to $T_{high}$ (Note 1)		2.415	-	2.585	2.436	-	2.564	
LM385-2.5		-	-	-	2.425	2.5	2.575	
$T_A = T_{low}$ to $T_{high}$ (Note 1)		-	-	-	2.400	-	2.600	
Minimum Operating Current	$I_{Rmin}$							μΑ
T <sub>A</sub> = 25°C		-	13	20	-	13	20	
$T_A = T_{low}$ to $T_{high}$ (Note 1)		-	-	30	-	-	30	
Reverse Breakdown Voltage Change with Current	$\Delta V_{(BR)R}$							mV
$I_{Rmin} \leq I_{R} \leq 1.0 \text{ mA}, T_{A} = +25^{\circ}\text{C}$	, ,	-	-	1.0	-	-	2.0	
$T_A = T_{low}$ to $T_{high}$ (Note 1)		-	-	1.5	-	-	2.5	
$1.0 \text{ mA} \leq I_R \leq 20 \text{ mA}, T_A = +25^{\circ}\text{C}$		-	-	10	-	-	20	
$T_A = T_{low}$ to $T_{high}$ (Note 1)		-	-	20	-	-	25	
Reverse Dynamic Impedance $I_R = 100 \mu A, T_A = +25 ^{\circ} C$	Z		0.6	-	-	0.6	-	Ω
Average Temperature Coefficient 20 $\mu$ A $\leq$ I <sub>R</sub> $\leq$ 20 mA, T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 1)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/°C
Wideband Noise (RMS) $I_R = 100 \ \mu\text{A}, \ 10 \ \text{Hz} \le f \le 10 \ \text{kHz}$	n	-	120	-	-	120	-	μV
Long Term Stability $I_R = 100 \ \mu\text{A}, \ T_A = +25 ^{\circ}\text{C} \pm 0.1 ^{\circ}\text{C}$	S	-	20	=	-	20	-	ppm/ kHR

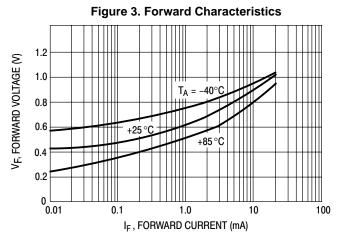
**NOTES:** 1.  $T_{low}$  = - 40°C for LM285-1.2, LM285-2.5 = 0°C for LM385-1.2, LM385B-1.2, LM385-2.5, LM385B-2.5

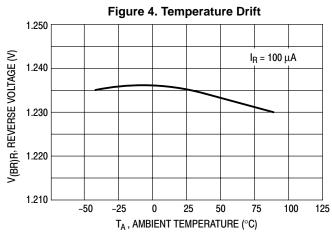
 $\begin{array}{lll} T_{high} &=& +85^{\circ}\text{C for LM285-1.2, LM285-2.5} \\ &=& +70^{\circ}\text{C for LM385-1.2, LM385B-1.2, LM385-2.5, LM385B-2.5} \end{array}$ 

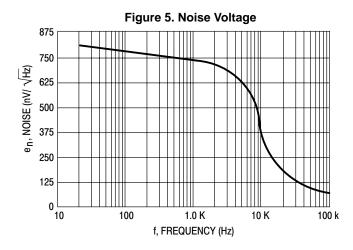
#### **TYPICAL PERFORMANCE CURVES FOR LM285-1.2/385-1.2/385B-1.2**

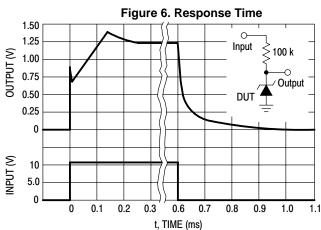




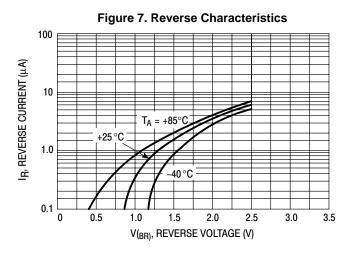


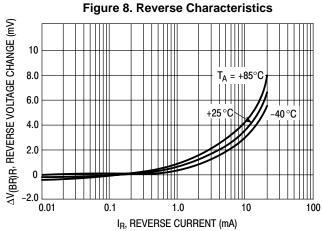


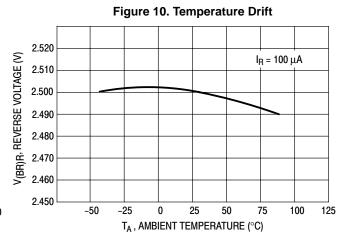


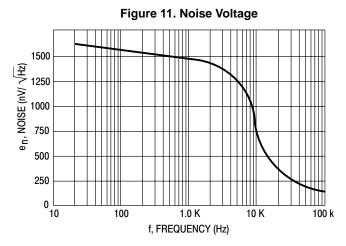


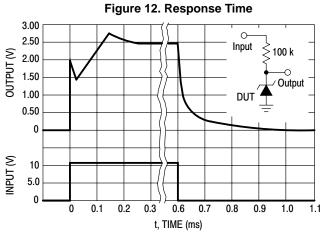
#### **TYPICAL PERFORMANCE CURVES FOR LM285-2.5/385-2.5/385B-2.5**







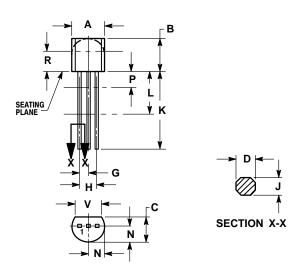




#### **PACKAGE DIMENSIONS**

#### PLASTIC PACKAGE **Z SUFFIX**

CASE 29-11 **ISSUE AL** 



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

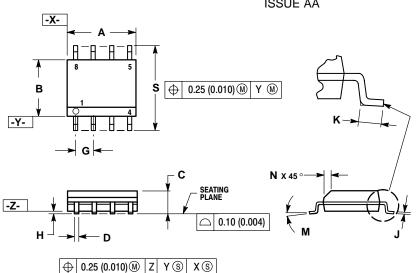
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
٦	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

#### **PLASTIC PACKAGE D SUFFIX**

CASE 751-07 **ISSUE AA** 



- OTICS:
   DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: MILLIMETER.
   DIMENSION A AND B DO NOT INCLUDE MOLD
- PROTRUSION.

  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
  6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	BSC	0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
M	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

# **Notes**

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